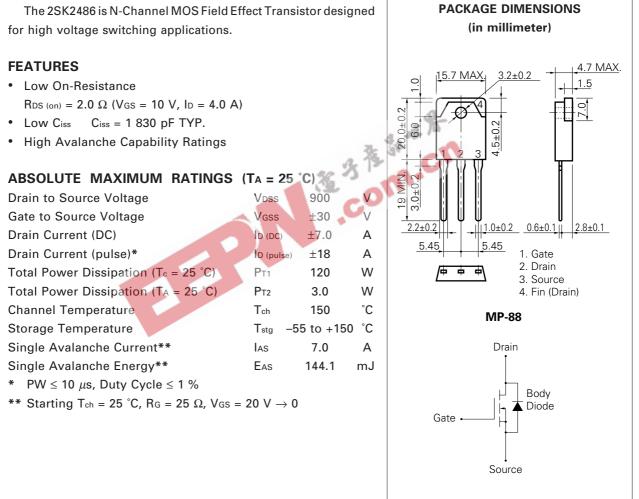
DATA SHEET



MOS FIELD EFFECT TRANSISTOR 2SK2486

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

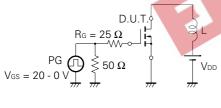
DESCRIPTION

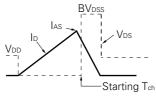


ELECTRICAL	CHARACTERISTICS	(TA = 25 °C)
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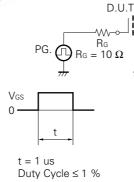
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS (on)		1.4	2.0	Ω	$V_{GS} = 10 V, I_{D} = 4.0 A$
Gate to Source Cutoff Voltage	VGS (off)	2.5		3.5	V	$V_{DS} = 10 V, I_{D} = 1 mA$
Forward Transfer Admittance	y _{fs}	2.5			S	$V_{DS} = 20 V, I_{D} = 4.0 A$
Drain Leakage Current	IDSS			100	μA	$V_{DS} = V_{DSS}, V_{GS} = 0$
Gate to Source Leakage Current	lgss			±100	nA	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0$
Input Capacitance	Ciss		1 830		pF	Vds = 10 V
Output Capacitance	Coss		250		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		40		pF	f = 1 MHz
Turn-On Delay Time	td (on)		30		ns	ID = 4.0 A
Rise Time	tr		15		ns	$V_{GS} = 10 V$
Turn-Off Delay Time	td (off)		110		ns	Vdd = 150 V
Fall Time	tr		20		ns	$R_G = 10 \Omega$
Total Gate Charge	Q _G		55		nC	ID = 7.0 A
Gate to Source Charge	Qgs		10		nC	VDD = 450 V
Gate to Drain Charge	Qgd		25	23	nC	Vgs = 10 V
Body Diode Forward Voltage	VF (S-D)		1.0	3	V	IF = 7.0 A, VGS = 0
Reverse Recovery Time	trr		800	00	ns	IF = 7.0 A, VGS = 0
Reverse Recovery Charge	Qrr	4.	4.8		μC	di/dt = 50 A/µs

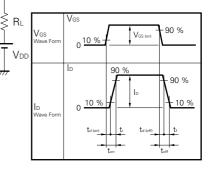
Test Circuit 1 Avalanche Capability



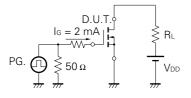


Test Circuit 2 Switching Time

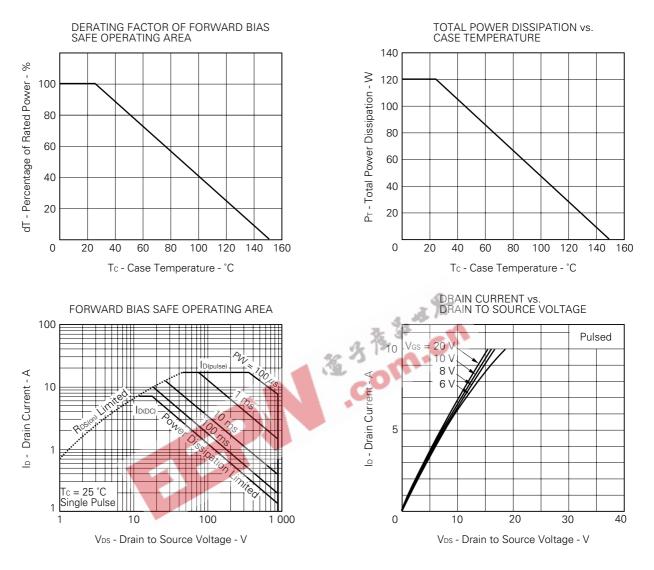




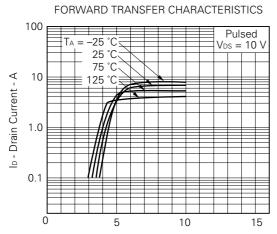
Test Circuit 3 Gate Charge



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.



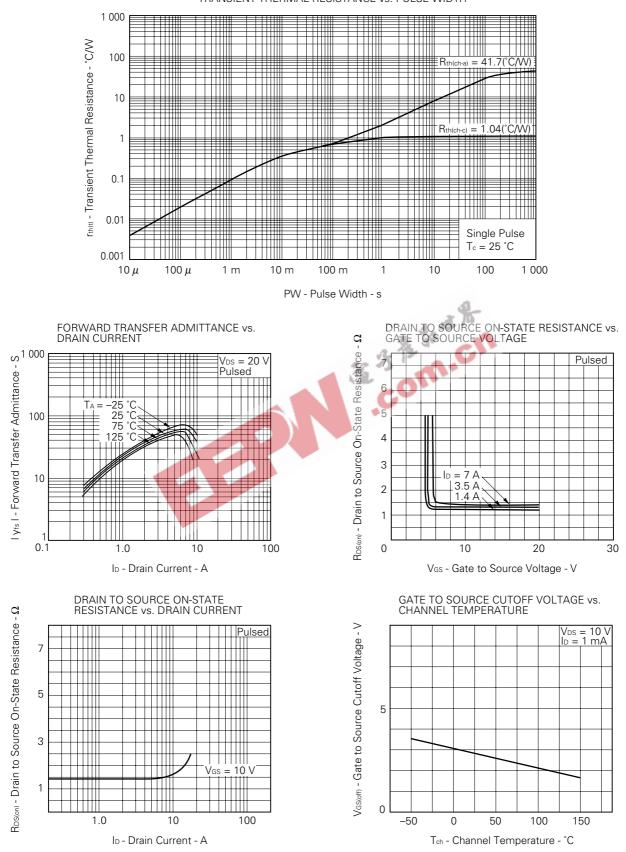
TYPICAL CHARACTERISTICS (T_A = 25 $^{\circ}$ C)

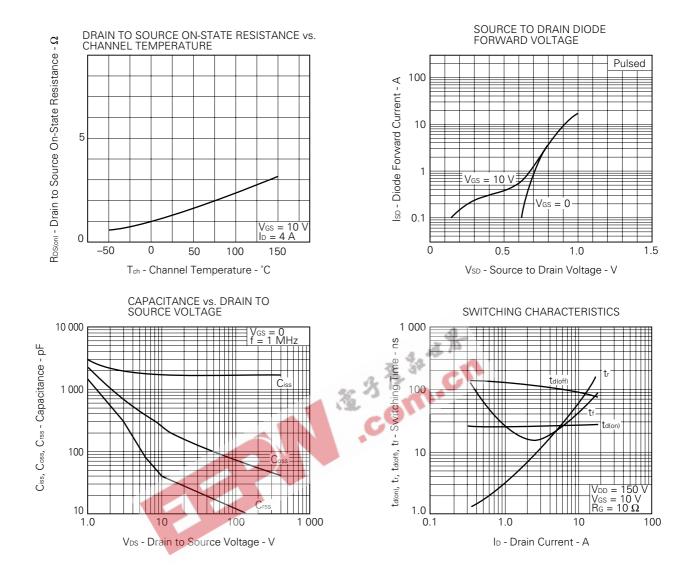


V_{GS} - Gate to Source Voltage - V



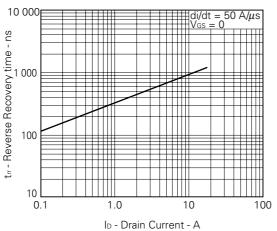
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

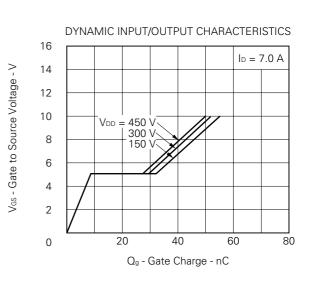


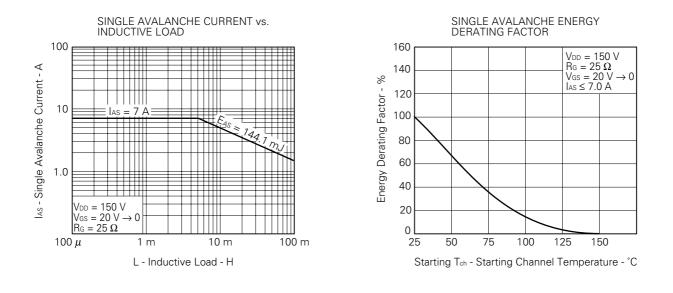




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REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037



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Anti-radioactive design is not implemented in this product.

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